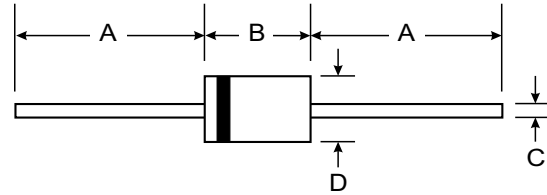


### Features

- Glass passivated chip junction
- Ultrafast reverse recovery time
- Low forward voltage drop
- Low leakage current
- Low switching losses, high efficiency
- High forward surge capability
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



DO-201AD		
Dim	Min	Max
A	25.40	—
B	7.20	9.50
C	1.20	1.30
D	4.80	5.30
All Dimensions in mm		

### Mechanical Data

- **Case:** DO-201AD  
Epoxy meets UL 94V-0 flammability rating
- **Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102  
E3 suffix for consumer grade, meets JESD 201 class 1A whisker test
- **Polarity:** Color band denotes cathode end

### Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

PARAMETER	SYMBOL	SBYV28-50	SBYV28-100	SBYV28-150	SBYV28-200	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	V	
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	V	
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	V	
Minimum reverse breakdown voltage at 100 μA	V <sub>BR</sub>	55	110	165	220	V	
Maximum average forward rectified current 0.375" (9.5 mm) lead lengths at T <sub>L</sub> = 85 °C	I <sub>F(AV)</sub>	3.5				A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	90				A	
Operating and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150				°C	
PARAMETER	TEST CONDITIONS	SYMBOL	SBYV28-50	SBYV28-100	SBYV28-150	SBYV28-200	UNIT
Maximum instantaneous forward voltage (1)	3.5 A T <sub>J</sub> = 25 °C T <sub>J</sub> = 150 °C	V <sub>F</sub>			1.1 0.89		V
Maximum DC reverse current at rated DC blocking voltage	T <sub>A</sub> = 25 °C T <sub>A</sub> = 100 °C	I <sub>R</sub>			5.0 300		μA
Maximum reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A T <sub>J</sub> = 25 °C	t <sub>rr</sub>			20		ns
Typical junction capacitance	4.0 V, 1 MHz	C <sub>J</sub>			20		pF

#### Note:

(1) Pulse test: t<sub>p</sub> = 300 μs, duty cycle ≤ 2 %



## RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

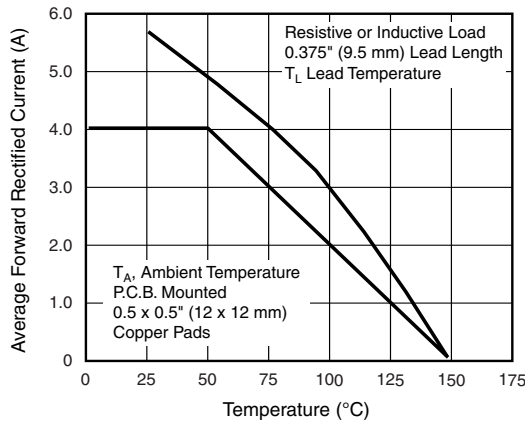


Figure 1. Forward Current Derating Curves

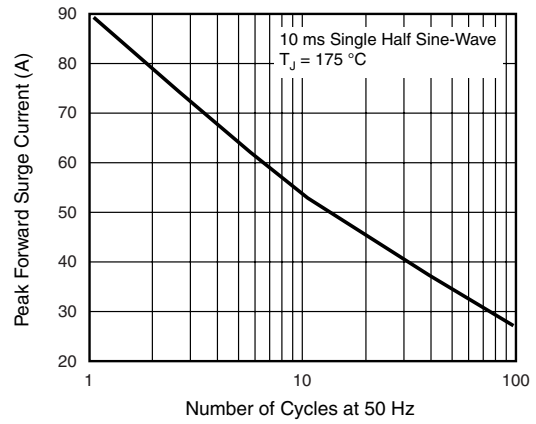


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

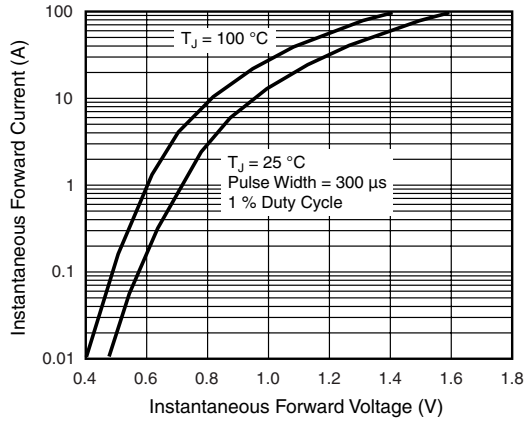


Figure 3. Typical Instantaneous Forward Characteristics

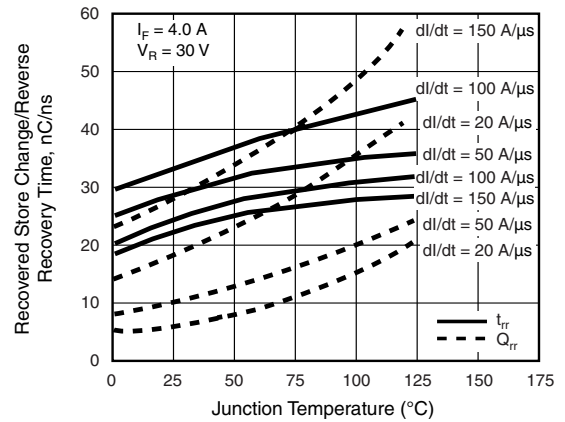


Figure 5. Reverse Switching Characteristics

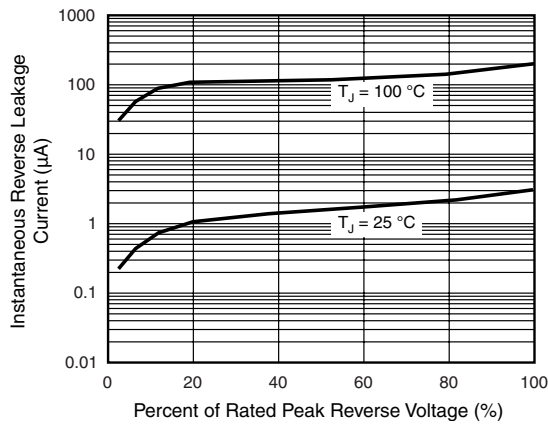


Figure 4. Typical Reverse Leakage Characteristics

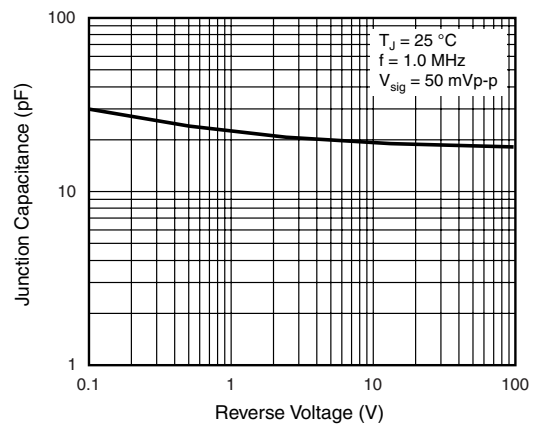


Figure 6. Typical Junction Capacitance